Choosing the Right Stepper Motor Driver

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Pete Millett – Staff Technical Marketing Engineer



2014–Present

- MPS Staff Technical Marketing Engineer for motor driver ICs
- Responsible for new product definitions as well as application engineering

2005-2013

- Systems Engineer and Systems Manager at Texas Instruments
- Product definition and systems engineering for motor driver ICs (DRV8XXX)

1982–2005

• Board-level hardware design engineer at various computer and consumer electronics companies



Stepper Motor Basics – Operational Review

Stepper Motor Driver Datasheet Specs

Finding the Right Stepper Motor Driver

Summary / Q&A



Stepper Motor Basics



Stepper Motor Construction







Images from www.allaboutcircuits.com

Permanent Magnet Stepper Motor

Hybrid Stepper Motor



Driving a Stepper Motor



MPS

Step Modes and Microstepping





Stepper Motor Driver ICs



Stepper Driver ICs: What's Inside (Simple)





Stepper Driver ICs: What's Inside (Advanced)



Stepper Driver ICs: Basic Features



FEATURES

- Wide 4.5V to 35V Input Voltage Range
- Two Internal Full-Bridge Drivers
- Internal Current Sensing and Regulation
- Low On Resistance (HS: 195mΩ, LS: 170mΩ)
- No Control Power Supply Required
- Simple Logic Interface
- 3.3V and 5V Compatible Logic Supply
- Step Modes from Full-Step to Eighth-Step
- 2.5A Output Current
- Automatic Current Decay
- Over-Current Protection (OCP)
- Input Over-Voltage Protection (OVP)
- Thermal Shutdown and Under-Voltage Lockout (UVLO) Protection
- Fault Indication Output
- Available in QFN-24 (5mmx5mm) and Thermally Enhanced TSSOP-28 Packages

• Wide	4.5V to 35V Input Voltage Range	This is the input power supply voltage range that drives the motor.
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•	2.5A Output Current	This current rating is the amount of current that the driver is capable
		of driving into the windings. It can be very misleading!

 Low On Resistance (HS: 195mΩ, LS: 170mΩ)
 This is the internal resistance of the MOSFETs in the H-bridge. It is usually a typical number at room temperature.

3.3V and 5V Compatible Logic Supply
 No Control Power Supply Required
 The logic input pins may be compatible with different logic levels, and the part may or may not have a separate logic supply input.



- Internal Current Sensing and Regulation
 Older stepper motor drivers use an external shunt to regulate current.
- Step Modes from Full-Step to Eighth-Step Different drivers support different step modes or degrees of microstepping.

https://www.monolithicpower.com/en/why-microstepping-isnt-as-good-as-you-think

Automatic Current Decay
 Accurate current control requires consideration of current decay.
 https://media.monolithicpower.com/document/AN120_Understanding_MP6500.pdf

- Over-Current Protection (OCP)
- Input Over-Voltage Protection (OVP)
- Thermal Shutdown and Under-Voltage Lockout (UVLO) Protection

Various protection features are available.

- Fault Indication Output
- Available in QFN-24 (5mmx5mm) and Thermally Enhanced TSSOP-28 Packages
 Package size may be important in your PCB design.



Stepper Driver Current Ratings



Peak	Highest permitted instantaneous current before OCP -or- highest normal winding current
Maximum	Highest normal winding current
Continuous	Highest continuous winding current -or- highest normal winding current
Average	Highest average winding current
RMS	Highest RMS winding current, usually- 0.707 times the peak or maximum current
Full scale	Highest normal winding current



Power Dissipation





P	VIN = 24V, I _{OUT} = 1A, T _J = 25°C	0.195	0.22	Ω
N _{HS}	$VIN = 24V, I_{OUT} = 1A,$ T _J = 85°C	0.25		Ω
P	$VIN = 24V, I_{OUT} = 1A, T_J = 25^{\circ}C$	0.17	0.21	Ω
N _{LS}	VIN = 24V, I _{OUT} = 1A, T _J = 85°C	0.25		Ω
	R _{HS}	$R_{HS} = \frac{VIN = 24V, I_{OUT} = 1A, T_{J} = 25^{\circ}C}{VIN = 24V, I_{OUT} = 1A, T_{J} = 85^{\circ}C}$ $R_{LS} = \frac{VIN = 24V, I_{OUT} = 1A, T_{J} = 25^{\circ}C}{VIN = 24V, I_{OUT} = 1A, T_{J} = 25^{\circ}C}$	$R_{HS} = \begin{bmatrix} VIN = 24V, I_{OUT} = 1A, & 0.195 \\ T_{J} = 25^{\circ}C & 0.195 \\ VIN = 24V, I_{OUT} = 1A, & 0.25 \\ T_{J} = 85^{\circ}C & 0.25 \\ \hline R_{LS} = \begin{bmatrix} VIN = 24V, I_{OUT} = 1A, & 0.17 \\ T_{J} = 25^{\circ}C & 0.17 \\ VIN = 24V, I_{OUT} = 1A, & 0.25 \\ \hline VIN = 24V, I_{OUT} = 1A, & 0.25 \\ \hline VIN = 24V, I_{OUT} = 1A, & 0.25 \\ \hline R_{LS} = 85^{\circ}C \\$	$R_{HS} = \begin{bmatrix} VIN = 24V, I_{OUT} = 1A, & 0.195 & 0.22 \\ T_{J} = 25^{\circ}C & 0.195 & 0.22 \\ VIN = 24V, I_{OUT} = 1A, & 0.25 \\ T_{J} = 85^{\circ}C & 0.17 & 0.21 \\ R_{LS} = \begin{bmatrix} VIN = 24V, I_{OUT} = 1A, & 0.17 & 0.21 \\ VIN = 24V, I_{OUT} = 1A, & 0.25 \\ VIN = 24V, I_{OUT} = 1A, & 0.25 \\ VIN = 24V, I_{OUT} = 1A, & 0.25 \end{bmatrix}$

MP6500: Total Effective Resistance = \sim 353m Ω

MOTOR D	RIVER OUTPUTS (AOUT1, AOUT	r2, BOUT1, BOUT2)		
		T _J = 25°C, I _O = -1 A	450 550	mΩ
R _{DS(ONH)}	High-side FET on resistance	T _J = 125°C, I _O = -1 A	700 850	mΩ
		T _J = 150°C, I _O = -1 A	780 950	mΩ
		$T_{\rm J}$ = 25°C, $I_{\rm O}$ = 1 A	450 550	mΩ
R _{DS(ONL)}	Low-side FET on resistance	T _J = 125°C, I _O = 1 A	700 850	mΩ
		T _J = 150°C, I _O = 1 A	780 950	mΩ

Competitor: Total Effective Resistance = ~900mΩ



A Problem: R_{DS(ON)} vs. Temperature









Static Losses $P_Q = V_{IN} \times I_Q$



 $\leftarrow t_{R} \rightarrow \leftarrow t_{F} \rightarrow$



Total Power $P = P_R + P_S + P_Q$



MP6500 Total Power Dissipation Calculation

Input supply voltage	V _{IN}		4.5	24	35	V
Quiescent current	Ι _Q	VIN = 24V, nENBL = 0, nSLEEP = 1, with no load		1.5	5	mA
	I _{SLEEP}	VIN = 24V, nSLEEP = 0			1	μA

	P	VIN = 24V, I _{OUT} = 1A, T _J = 25°C	0.195	0.22	Ω
Output on registence	T'HS	VIN = 24V, I _{OUT} = 1A, T _J = 85°C	0.25		Ω
Output on resistance	R	VIN = 24V, I _{OUT} = 1A, T _J = 25°C	0.17	0.21	Ω
	N _{LS}	VIN = 24V, I _{OUT} = 1A, T _J = 85°C	0.25		Ω

Resistive Losses: $P_R = 1.41A^2 \times 353m\Omega = 705mW$ per H-bridge Switching Losses: Estimated $P_{SW} = ~70mW$ per H-bridge Static Losses: $P_Q = 24V \times 1.5mA = 36mW$

Total Power: 2 x 755mW + 2 x 70mW + 36mW = 1.58W



Thermal Resistance & Models



Simple Estimation: Die Temperature = Ambient Temperature + ($P \times \Theta_{JA}$)



PCB Design for Power Dissipation

Table 7 — JESD51-7 High Thermal Conductivity Leaded SMT Test Board Parameters [8]

Dimension	Specification	User
Board Finish Thickness	1.60 mm ± 10%	
Board Dimension (pkg length < 27 mm)	76.2 mm x 114.3 mm	
Board Dimension (27 mm \leq pkg length \leq 48 mm)	101.6 mm x 114.3 mm	
Board material	FR-4	
Trace Copper Thickness	0.070 mm ± 20%	
Trace Width, Finished	0.25 mm \pm 10% for \geq 0.50 mm pin pitch Lead width for < 0.50 mm pin pitch	
Trace Coverage Area (Total)		
Power/Ground Thickness	35 µm (1oz) copper +0/-20%	



Effect of Layer Count & Planes

MP6500 Driving a 2A Peak Stepper Motor



2 Layers



4 Layers (2 Planes)



Current Ratings Revisited



Datasheet Current Ratings Are Almost Meaningless!

Thermal Resistance ⁽⁴⁾	θ _{JA}	θ_{JC}	
QFN-25 (5mmx5mm)	36	8	°C/W
TSSOP-28 EP	32	6	°C/W

 $\begin{array}{l} \textbf{MP6500} - \textbf{Current rating is "2.5A maximum"} \\ \textbf{Effective } \textbf{R}_{\text{DS(ON)}} \text{ is 380m} \Omega \end{array}$

		PWP (HTSSOP)	RGE (VQFN)	
		24 PINS	24 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	30.9	40.7	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	25.2	31.1	°C/W
R _{0JB}	Junction-to-board thermal resistance	11.3	17.9	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	0.4	0.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	11.3	17.8	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	3.1	4.3	°C/W

Competitor – Current rating is "2.4A peak, 1.5A full scale"

Effective $R_{DS(ON)}$ is 900m Ω



	I _{VM}	VM operating supply current	DRVOFF = 0, nSLEEP = 1, No output	5	7	mA
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		T _J = 25°C, I _O = -1 A	450	550	mΩ
R _{DS(ONH)}	High-side FET on resistance	T _J = 125°C, I _O = -1 A	700	850	mΩ
	T _J = 150°C, I _O = -1 A	780	950	mΩ	
		$T_{\rm J} = 25^{\circ}$ C, $I_{\rm O} = 1$ A	450	550	mΩ
R _{DS(ONL)}	Low-side FET on resistance	T _J = 125°C, I _O = 1 A	700	850	mΩ
(,		T _J = 150°C, I _O = 1 A	780	950	mΩ

Resistive Losses: $P_R = 1.41A^2 \times 900m\Omega = 1.79W$ Switching Losses: Estimated $P_{SW} = ~70mW$ Static Losses: $P_Q = 24V \times 5mA = 120mW$

Total Power: 2 x 1.79W + 2 x 70mW + 120mW = 3.83W



MP6500 (TSSOP) – 1.58W x 32°C/W = 51°C temperature rise $T_J = 150$ °C when $T_A = 99$ °C

Competitor (TSSOP) – 3.83W x 30.9°C/W = 118°C temperature rise $T_J = 150$ °C when $T_A = 32$ °C



At Room Temperature (25°C):

MP6500 (TSSOP) – Max Power = $(150^{\circ} - 25^{\circ}) / 32^{\circ}C/W = 3.9W$ Maximum Current per Winding = 2.3A RMS (3.2A peak)

Competitor (TSSOP) – Max Power = (150° - 25°) / 30.9°C/W = 4W Maximum Current per Winding = 1.4A RMS (2A peak)

At High Temperatures (85°C):

MP6500 (TSSOP) – Max Power = $(85^{\circ} - 25^{\circ}) / 32^{\circ}C/W = 2W$ Maximum Current per Winding = 1.6A RMS (2.3A peak)

Competitor (TSSOP) – Max Power = (85° - 25°) / 30.9°C/W = 2.1W Maximum Current per Winding = 1A RMS (1.4A peak)



...And It May Be Even Worse!







Image from www.dilbert.com



- Don't take all the information on a stepper driver datasheet at face value! (Not even mine!)
- Do your own calculations when it comes to the current rating needed
- Take into account PCB construction and ambient temperature

Please submit questions through the "Q&A" menu option in the Zoom app

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MonolithicPower.com/webinars

